



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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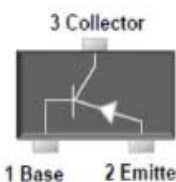
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Small Signal Product

350mW, PNP Small Signal Transistor
FEATURES

- Epitaxial planar die construction
- Surface device type mounting
- Moisture sensitivity level 1
- Matte Tin (Sn) lead finish with Nickel (Ni) underplate
- Pb free version and RoHS compliant
- Packing code with suffix "G" means green compound (halogen-free)


SOT-23

MECHANICAL DATA

- Case: SOT- 23, molded plastic
- Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- High temperature soldering guaranteed: 260°C/10s
- Weight: 8 mg (approximately)
- Marking Code: 3E.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation	P _D	350	mW
Collector-Base Voltage	V _{CB0}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C	-200	mA
Thermal Resistance Junction-Ambient	R _{θJA}	357	°C/W
Junction and Storage Temperature Range	T _J , T _{STG}	-55 to + 150	°C

Notes:1. Valid provided that electrodes are kept at ambient temperature

PARAMETER	SYMBOL	MIN	MAX	UNIT	
Collector-Base Breakdown Voltage	I _C = 10 μA I _E = 0	V _{(BR)CBO}	-40	-	V
Collector-Emitter Breakdown Voltage	I _C = -1 mA I _B = 0	V _{(BR)CEO}	-40	-	V
Emitter-Base Breakdown Voltage	I _E = -10 μA I _C = 0	V _{(BR)EBO}	-5	-	V
Collector Base Cut-off Current	V _{CB} = -40 V	I _{CBO}	-	-100	nA
Emitter Base Cut-off Current	V _{EB} = -6 V	I _{EBO}	-	-50	nA
DC Current Gain	V _{CE} = -1 V I _C = -0.1 mA	h _{FE}	60	300	
	V _{CE} = -1 V I _C = -1 mA		80		
	V _{CE} = -1 V I _C = -10 mA		100		
	V _{CE} = -1 V I _C = -50 mA		60		
	V _{CE} = -1 V I _C = -100 mA		30		
Collector-Emitter Saturation Voltage	I _C = -10 mA I _B = -1 mA	V _{CE(sat)}	-	-0.25	V
	I _C = -50 mA I _B = -5 mA		-	-0.4	
Base-Emitter Saturation Voltage	I _C = -10 mA I _B = -1 mA	V _{BE(sat)}	-0.65	-0.85	V
	I _C = -50 mA I _B = -5 mA		-	-0.95	
Gain-Bandwidth Product	V _{CE} = -20 V I _C = -10 mA f = 100MHz	f _T	250	-	MHz
Output Capacitance	V _{CB} = -5 V I _E = 0 f = 1MHz	C _{obo}	-	4.5	pF
Delay time	V _{CC} = -3 V V _{BE} = -0.5 V I _C = -10 mA	t _d	-	35	ns
Rise time	I _{B1} = -1.0 mA	t _r	-	35	ns
Storage time	V _{CC} = -3 V I _C = -10 mA	t _s	-	225	ns
Fall time	I _{B1} = I _{B2} = -1.0 mA	t _f	-	75	ns

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RATINGS AND CHARACTERISTICS CURVES

($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig. 1 Capacitance

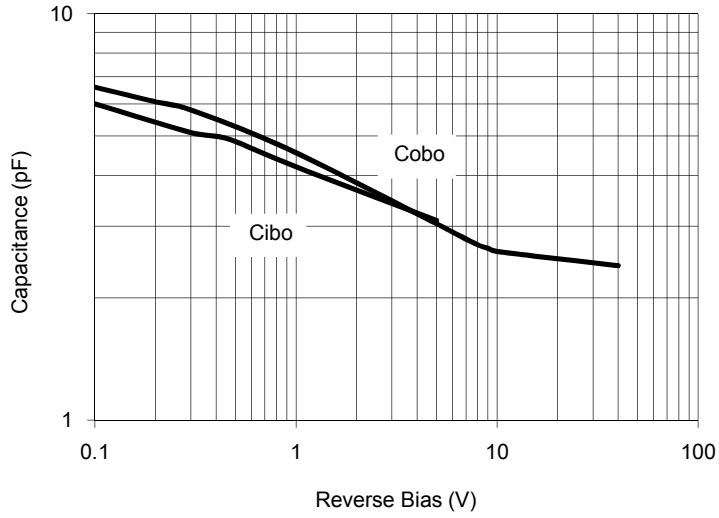


Fig. 2 Charge Data

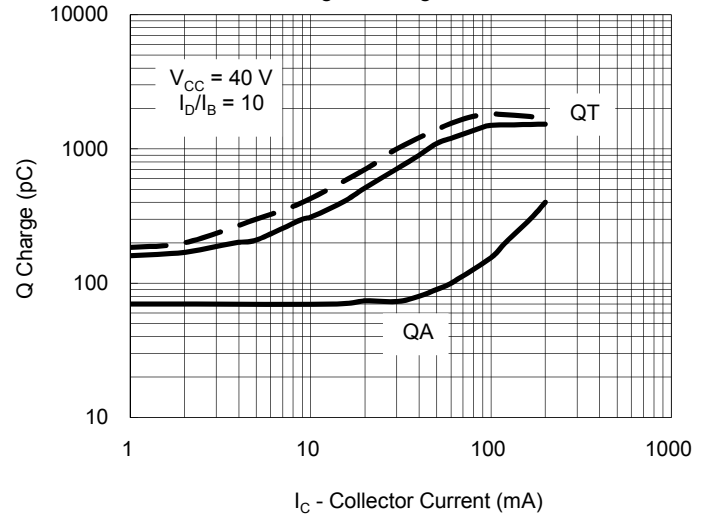


Fig. 3 Turn - On Time

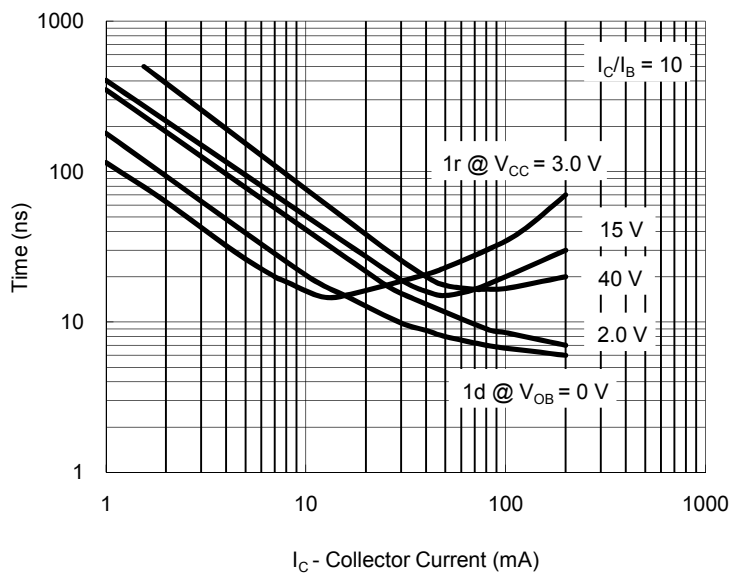


Fig. 4 Fall Time

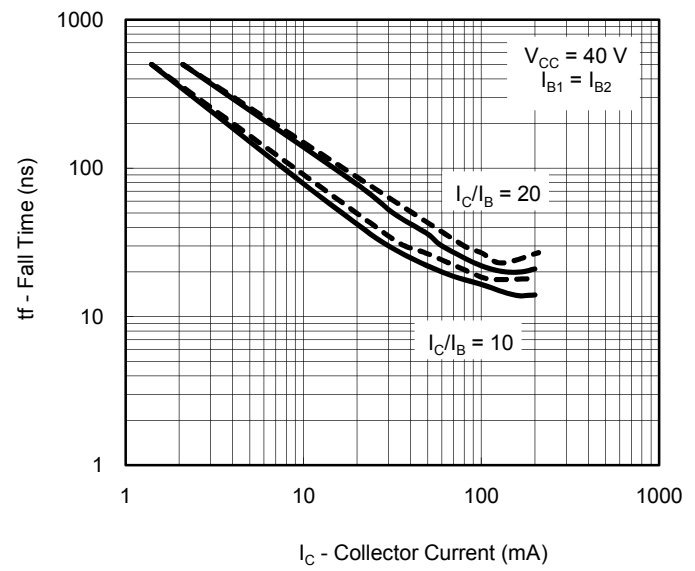


Fig. 5 Noise Figure vs. Frequency

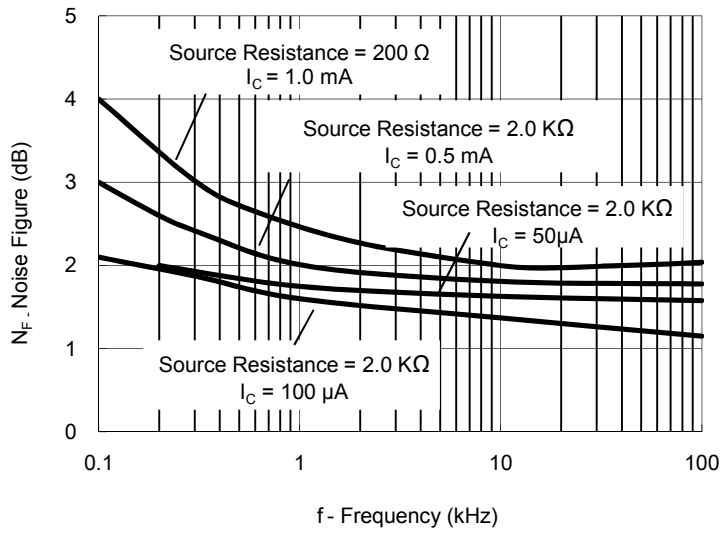
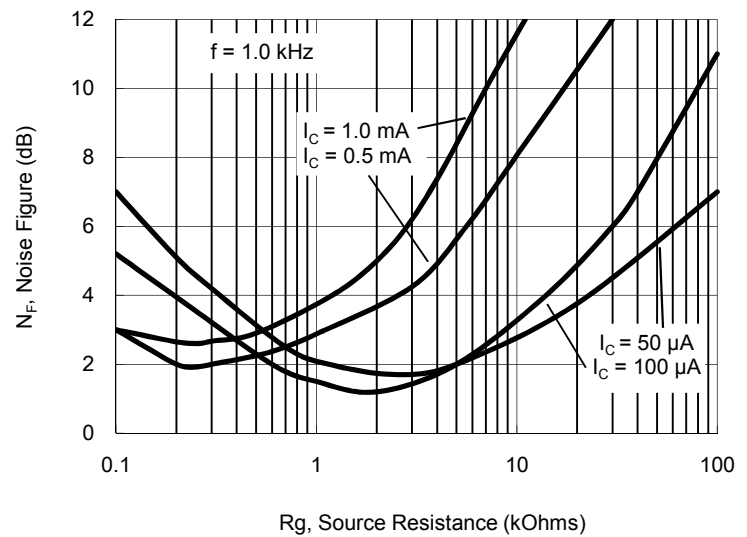


Fig. 6 Noise Figure vs. Source Resistance



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h Parameters ($V_{CE} = -10 V_{DC}$, $f = 1.0 \text{ kHz}$, $T_A = 25^\circ\text{C}$)

Fig. 7 Current Gain

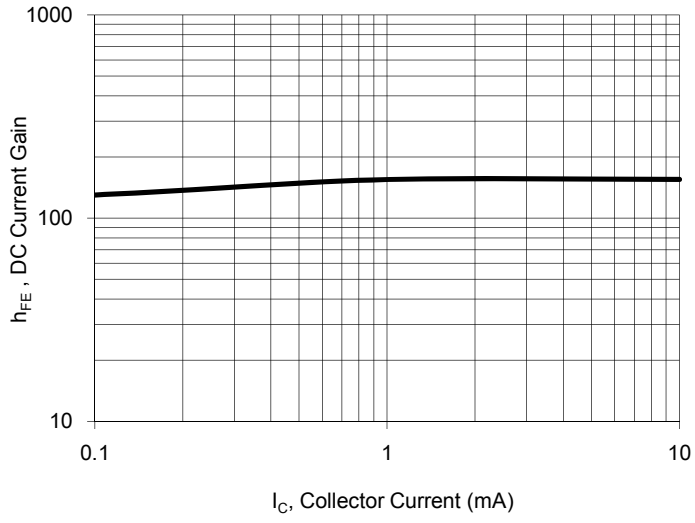


Fig. 8 Output Admittance

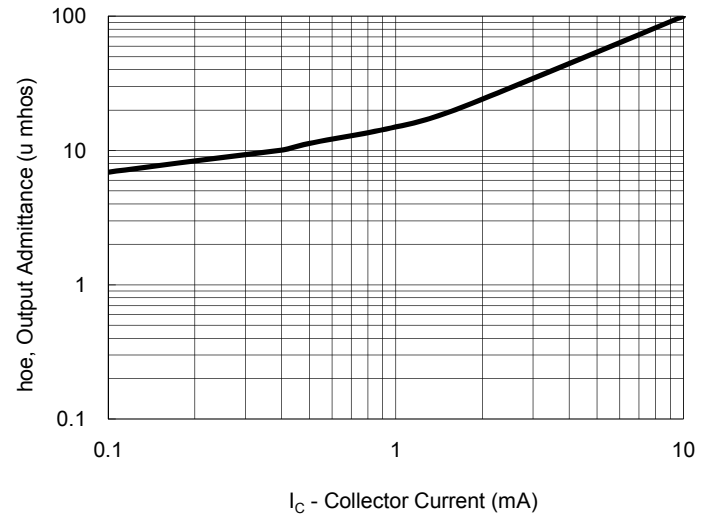


Fig. 9 Input Impedance

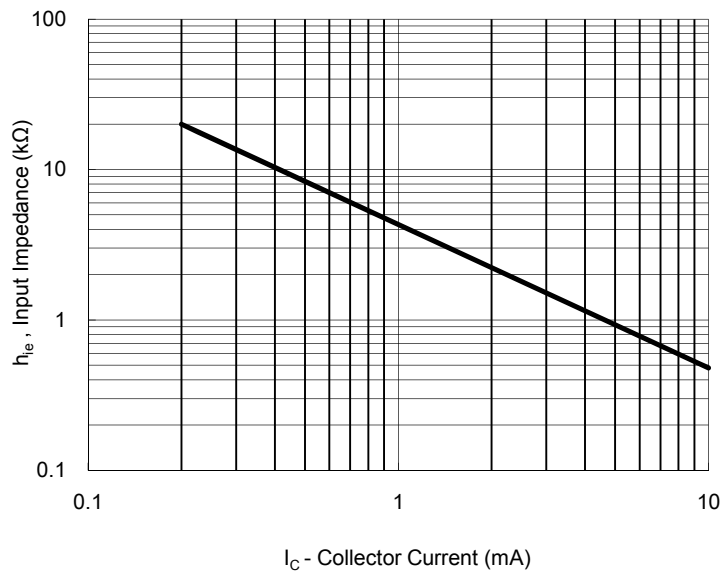


Fig. 10 Voltage Feedback Ratio

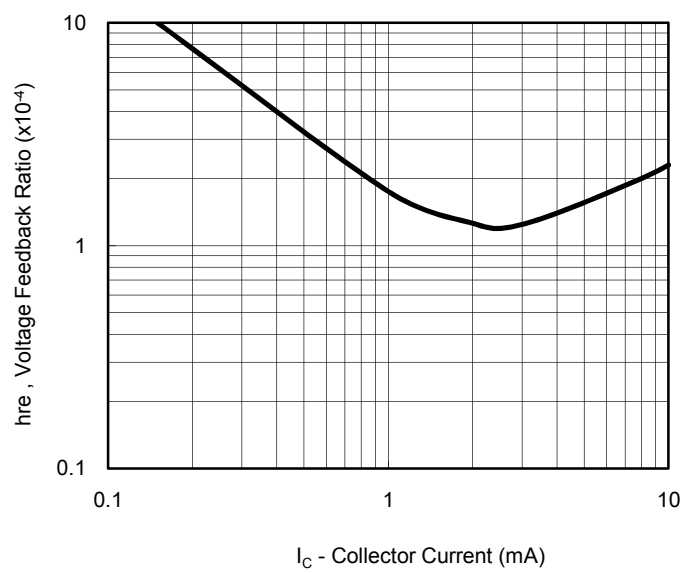


Fig. 11 "ON" Voltages

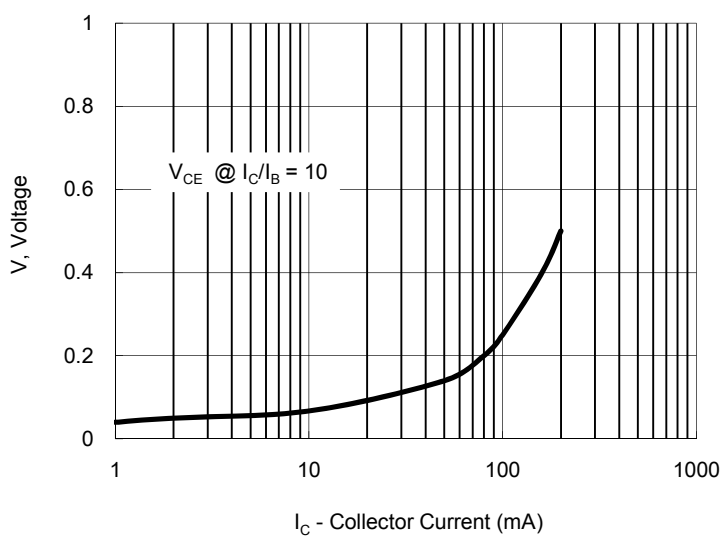
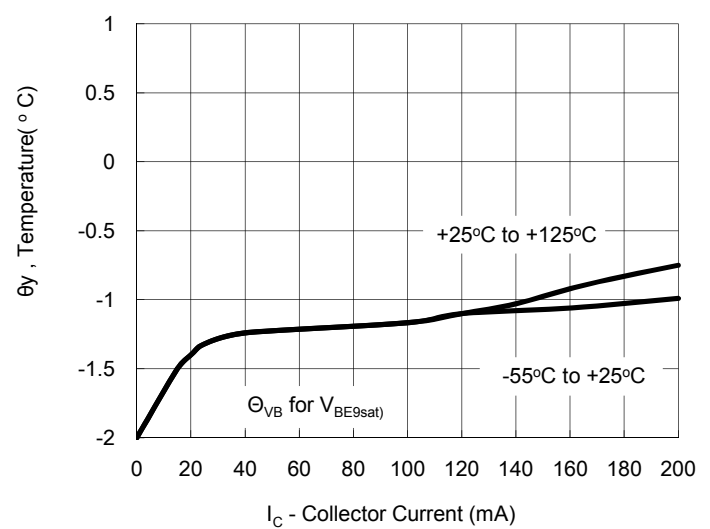


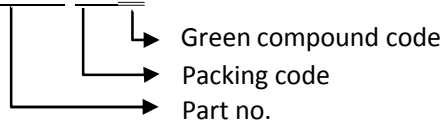
Fig. 12 Temperature Coefficients



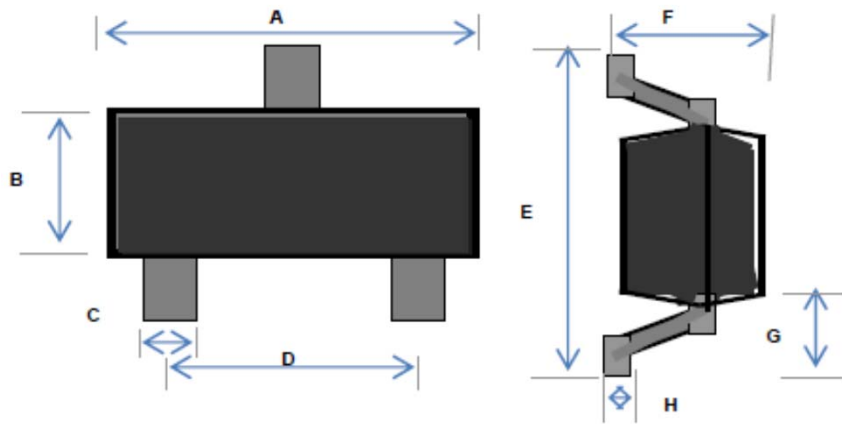
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ORDER INFORMATION (EXAMPLE)

MMBT3906L RFG

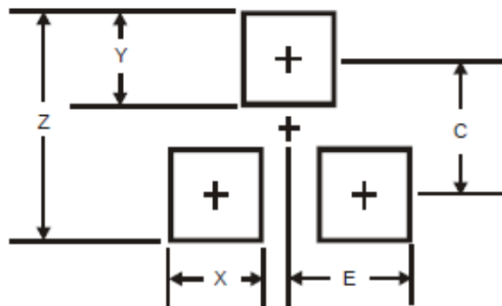


PACKAGE OUTLINE DIMENSIONS
SOT-23



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	2.70	3.10	0.106	0.122
B	1.10	1.50	0.043	0.059
C	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
E	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022 REF	
H	0.10 REF		0.004 REF	

SUGGEST PAD LAYOUT



DIM	Unit (mm)	Unit (inch)
	TYP	TYP
Z	2.90	0.114
X	0.80	0.031
Y	0.90	0.035
C	2.00	0.079
E	1.35	0.053

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